# Switching (30V, 5.0A) **SP8K1**

## Features

1) Low on-resistance.

2) Built-in G-S Protection Diode.

3) Small and Surface Mount Package (SOP8).

#### Application

Power switching, DC / DC converter.

#### Structure

Silicon N-channel MOS FET

## •External dimensions (Unit : mm)



#### •Absolute maximum ratings (Ta=25°C) It is the same ratings for the Tr. 1 and Tr. 2

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Parameter		Symbol	Limits	Unit	
Drain-source voltage		VDSS	30	V	
Gate-source voltage		V <sub>GSS</sub>	20	V	
Drain current	Continuous	ID	±5.0	А	
	Pulsed	IDP	±20	A *1	
Source current	Continuous	ls	1.6	A	
(Body diode)	Pulsed	I <sub>SP</sub>	6.4	A *1	
Total power dissipation		PD	2	W *2	
Channel temperature		Tch	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

\*1 Pw≤10µs, Duty cycle≤1% \*2 MOUNTED ON A CERAMIC BOARD.

## •Equivalent circuit



\*A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use the protection circuit when the fixed voltages are exceeded.

## •Thermal resistance (Ta=25°C)

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth (ch-a)	62.5	°C / W *
*MOUNTED ON A CERAMIC BOARD.			

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## Transistors

## •Electrical characteristics (Ta=25°C)

It is the same characteristics for the Tr. 1 and Tr. 2.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	lgss	-	-	10	μA	Vgs=20V, Vds=0V
Drain-source breakdown voltage	V(BR) DSS	30	-	-	V	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	IDSS	-	-	1	μA	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V
Gate threshold voltage	VGS (th)	1.0	-	2.5	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
Static drain-source on-state resistance	RDS (on)	-	36	51	mΩ	I <sub>D</sub> =5.0A, V <sub>GS</sub> =10V
		-	52	73		I <sub>D</sub> =5.0A, V <sub>GS</sub> =4.5V
		-	58	82		I <sub>D</sub> =5.0A, V <sub>GS</sub> =4V
Forward transfer admittance	Y <sub>fs</sub> *	3.0	-	_	S	I <sub>D</sub> =5.0A, V <sub>DS</sub> =10V
Input capacitance	Ciss	-	230	-	pF	VDS=10V
Output capacitance	Coss	-	80	_	pF	Vgs=0V
Reverse transfer capacitance	Crss	-	50	_	pF	f=1MHz
Turn-on delay time	td (on) *	-	6	_	ns	I <sub>D</sub> =2.5A, V <sub>DD</sub> ≒15V
Rise time	tr *	-	8	_	ns	V <sub>GS</sub> =10V
Turn-off delay time	t <sub>d (off)</sub> *	-	22	-	ns	RL=6Ω
Fall time	t <sub>f</sub> *	-	5	_	ns	R <sub>GS</sub> =10Ω
Total gate charge	Qg *	-	3.9	5.5	nC	V <sub>DD</sub> ≒15V
Gate-source charge	Qgs *	-	1.1	-	nC	V <sub>GS</sub> =5V
Gate-drain charge	Q <sub>gd</sub> *	-	1.4	_	nC	I <sub>D</sub> =5.0A

\*Pulsed

## •Body diode characteristics (Source-Drain Characteristics) (Ta=25°C)

It is the same characteristics for the Tr. 1 and Tr. 2.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	V <sub>SD</sub> *	-	_	1.2	V	Is=6.4A, V <sub>GS</sub> =0V
*Pulsod						

\*Pulsed

## SP8K1

## Transistors



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